PDTC114T series

NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = open

Rev. 08 — 9 February 2006

Product data sheet

1. Product profile

1.1 General description

NPN Resistor-Equipped Transistors (RET) family.

Table 1: Product overview

Type number	Package	PNP complement		
	Philips JEITA JEDEC			
PDTC114TE	SOT416	SC-75	-	PDTA114TE
PDTC114TK	SOT346	SC-59A	TO-236	PDTA114TK
PDTC114TM	SOT883	SC-101	-	PDTA114TM
PDTC114TS[1]	SOT54	SC-43A	TO-92	PDTA114TS
PDTC114TT	SOT23	-	TO-236AB	PDTA114TT
PDTC114TU	SOT323	SC-70	-	PDTA114TU

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- Built-in bias resistors
- Simplifies circuit design
- 100 mA output current capability
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Digital applications
- Controlling IC inputs

- Cost-saving alternative for BC847 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2: Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	50	V
Io	output current		-	-	100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ



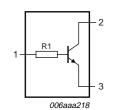
2. Pinning information

Table 3: Pinning

Pin	Description	Simplified outline	Symbol
SOT54			
1	input (base)		
2	output (collector)		1 2
3	GND (emitter)	001aab347	1 R1 3

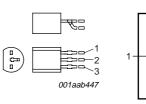
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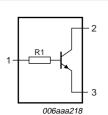
1	input (base)	
2	output (collector)	
3	GND (emitter)	1 2 3 001aab348



SOT54 variant

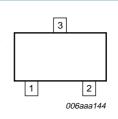
1	input (base)
2	output (collector)
3	GND (emitter)

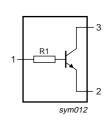




SOT23; SOT323; SOT346; SOT416

1	input (base)
2	GND (emitter)
3	output (collector)

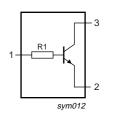




SOT883

1	input (base)
2	GND (emitter)
3	output (collector)





3. Ordering information

Table 4: Ordering information

	-auto-iii oraoriiig iiioriiiaaioii						
Type number	Package						
	Name	Description	Version				
PDTC114TE	SC-75	plastic surface mounted package; 3 leads	SOT416				
PDTC114TK	SC-59A	plastic surface mounted package; 3 leads	SOT346				
PDTC114TM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
PDTC114TS[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
PDTC114TT	-	plastic surface mounted package; 3 leads	SOT23				
PDTC114TU	SC-70	plastic surface mounted package; 3 leads	SOT323				

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

4. Marking

Table 5: Marking codes

Type number	Marking code [1]
PDTC114TE	24
PDTC114TK	24
PDTC114TM	DT
PDTC114TS	TC114T
PDTC114TT	*12
PDTC114TU	*24

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	50	V
V _{EBO}	emitter-base voltage	open collector		-	5	V
Io	output current			-	100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$		-	100	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C				
	SOT416		<u>[1]</u>	-	150	mW
	SOT346		<u>[1]</u>	-	250	mW
	SOT883		[2] [3]	-	250	mW
	SOT54		<u>[1]</u>	-	500	mW
	SOT23		<u>[1]</u>	-	250	mW
	SOT323		<u>[1]</u>	-	200	mW
T _{stg}	storage temperature			-65	+150	°C
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7: Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	SOT416		<u>[1]</u> -	-	833	K/W
	SOT346		<u>[1]</u> -	-	500	K/W
	SOT883		[2][3]	-	500	K/W
	SOT54		<u>[1]</u> _	-	250	K/W
	SOT23		<u>[1]</u> _	-	500	K/W
	SOT323		<u>[1]</u> -	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

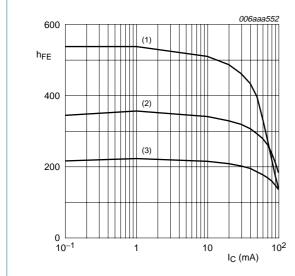
^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

7. Characteristics

Table 8: Characteristics

T_{amb} = 25 °C unless otherwise specified.

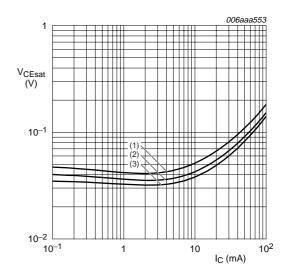
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	V _{CB} = 50 V; I _E = 0 A	-	-	100	nA
I _{CEO}	collector-emitter	$V_{CE} = 30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	1	μΑ
	cut-off current	$V_{CE} = 30 \text{ V; } I_{B} = 0 \text{ A;}$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$	-	-	100	nA
h _{FE}	DC current gain	$V_{CE} = 5 \text{ V}; I_{C} = 1 \text{ mA}$	200	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$	-	-	150	mV
R1	bias resistor 1 (input)		7	10	13	kΩ
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	2.5	pF





- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values



$$I_{\rm C}/I_{\rm B} = 20$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

8. Package outline

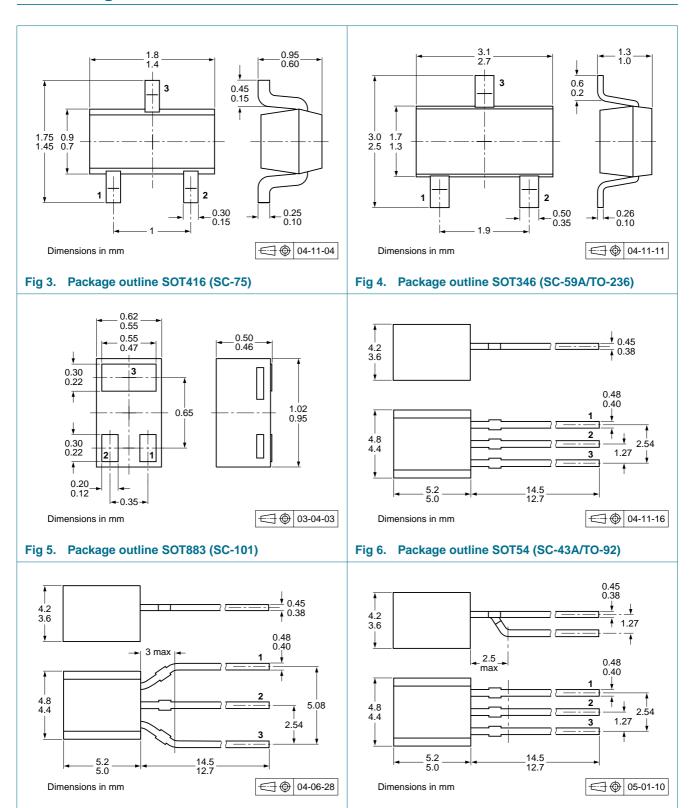
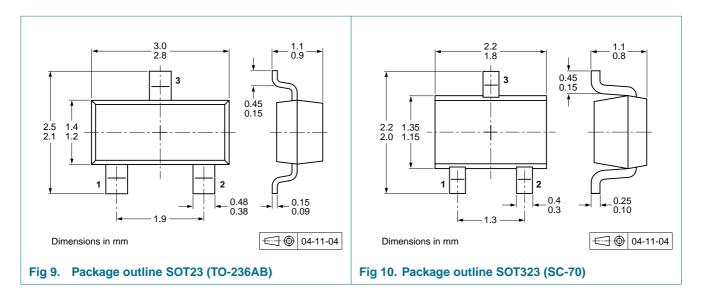


Fig 7. Package outline SOT54A

Fig 8. Package outline SOT54 variant



9. Packing information

Table 9: Packing methods
The indicated -xxx are the last three digits of the 12NC ordering code. [1]

Type number	Package	Description	Packing quantity		
			3000	5000	10000
PDTC114TE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTC114TK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135
PDTC114TM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315
PDTC114TS	SOT54	bulk, straight leads	-	-412	-
	SOT54A SOT54 variant	tape and reel, wide pitch	-	-	-116
		tape ammopack, wide pitch	-	-	-126
		bulk, delta pinning	-	-112	-
PDTC114TT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235
PDTC114TU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135

^[1] For further information and the availability of packing methods, see Section 15.

10. Revision history

Table 10: Revision history

Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
PDTC114T_SER_8	20060209	Product data sheet	-	-	PDTC114T_SER_7
Modifications:	information Type numbe Table 1 "Pro Section 1.2 Section 1.3 Figure 1, 2, Figure 3, 4, Section 9 "Formation or service or serv	of this data sheet has standard of Philips So er PDTC114TEF remoduct overview": EIAJ "Features": amended "Applications": amend 7 and 8: added 5, 6, 9 and 10: super Packing information": a "Trademarks": added	emiconductors. oved in table header and ded seded by minimiz	mended to JEITA	e new presentation and
PDTC114T_SER_7	20041011	Product specification	-	9397 750 14186	PDTC114T_SERIES_6
PDTC114T_SERIES_6	20040817	Product specification	-	9397 750 13664	PDTC114T_SERIES_5
PDTC114T_SERIES_5	20040119	Product specification	-	9397 750 11731	PDTC114T_SERIES_4
PDTC114T_SERIES_4	20030414	Product specification	-	9397 750 11011	PDTC114TE_2 PDTC114TK_2 PDTC114TS_2 PDTC114TT_3 PDTC114TU_3
PDTC114TU_3	19990416	Preliminary specification	-	9397 750 05599	PDTC114TU_2
PDTC114TU_2	19980519	Preliminary specification	-	9397 750 03908	PDTC114TU_1
PDTC114TU_1	19970716	Preliminary specification	-	9397 750 01149	-
PDTC114TT_3	19990416	Objective specification	-	9397 750 05598	PDTC114TT_2
PDTC114TT_2	19980519	Objective specification	-	9397 750 03912	PDTC114TT_1
PDTC114TT_1	19970714	Objective specification	-	9397 750 01371	-
PDTC114TS_2	19980518	Product specification	-	9397 750 03891	PDTC114TS_1
PDTC114TS_1	19970703	Product specification	-	9397 750 02297	-
PDTC114TK_2	19980519	Product specification	-	9397 750 03899	PDTC114TK_1

PDTC114T series

NPN resistor-equipped transistors; R1 = 10 k Ω , R2 = open



Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
PDTC114TK_1	19970528	Product specification	-	9397 750 01367	-
PDTC114TE_2	19980803	Product specification	-	9397 750 04123	PDTC114TE_1
PDTC114TE_1	19970711	Product specification	-	9397 750 02628	-



Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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- [2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
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